

# The flexible laser module

The structured light laser ZXS sets new standards for machine vision illumination due to its automated production in which all optical components are aligned by a high-accurracy robot.

The ZXS-laser reaches an unrivalled accuracy with its boresight error of less than 0.8 mrad.

The separated electronics enables the user to mount the laser individually. An OEM-Version with a customized electronics for the integration onto an existing PCB is also available.

# HIGHLIGHTS

- Industrial standard
- IP 67 (ZXS20) / IP 50 (ZXS10)
- Repeatable product performance due to automated production processes
- Highest reproducibility of beam quality
- Optical output power up to 200 mW
- Wavelengths from 405 830 nm
- Manually focusable (ZXS20)
- TTL modulation up to 150 kHz
- Analog intensity control

# APPLICATIONS

- Machine Vision
- Triangulation sensors
- 3D-Measurement
- High-precision positioning tasks

ORDER CODE										
Z <b>??</b>	-	XS <mark>20</mark>	-	?	-	?	-	?	-	?
Power		Product name Size of head		Electronics		F = focusable		Wavelength		Optics



## SYSTEM SPECIFICATIONS

Wavelength	nm
Wavelength tolerance	nm (typical)
Wavelength drift	nm / K (typical)
Available with optical head	
Output power ZXS10 (slp / elp)	mW
Output power ZXS20 (slp / elp)	mW
Output power ZXS20 (flp)	mW
Spatial mode	(typical)
RMS noise	(20 Hz to 20 MHz, typical)
Peak-to-Peak Noise	(20 Hz to 20 MHz, typical)
Boresight error <sup>(1)</sup>	mrad (typical)
Line orientation <sup>(2)</sup>	mrad
Pointing stability	µrad / K
Long-term power stability	(24 h)
Start-up time	sec
Laser operation mode	

405 nm	450 nm	520 nm	635-685 nm	785 nm	830 nm
±10 nm	±10 nm	-5 nm +10 nm	±10 nm	±10 nm	±4 nm
0,06 nm	0,02 nm	0,06 nm	0,25 nm	0,25 nm	0,25 nm
n. a.	≤ 45 mW	≤ 35 mW	≤ 100 mW	≤ 100 mW	≤ 100 mW
≤ 160 mW	≤ 60 mW	≤ 40 mW	≤ 100 mW	≤ 80 mW	≤ 200 mW
≤ 120 mW	≤ 45 mW	≤ 30 mW	≤ 90 mW	≤ 60 mW	≤ 150 mW
Single Transverse Mode					
< 0.5 %					
< 1 %					
< 0.8 mrad (1	fixed focus)				
< 10 mrad					
< 10 µrad / K					
±3 % over operating temperature range					
<2s					
APC					

### ELECTRICAL SPECIFICATIONS

Operating voltage	9 - 30 VDC 9 - 30 VDC 9 - 30 VDC 5 - 30 VDC 5 - 30 VDC 5 - 30 VDC 5 - 30 VDC
Operating current (max. at 25 °C)	< 300 mA < 300 mA < 300 mA < 400 mA < 500 mA < 500 mA
Protection	Over temperature protection and LED pre-failure indicator, reverse polarity and transient protection (ESD, burst & surge)
Electrical isolation	Potential-free housing
Connection	5-pin M12 plug; cable with flying leads or customized
Power consumption	< 2.7 W < 2.7 W < 2.7 W < 2.7 W < 2.5 W < 2.5 W
Communication interfaces	I²C, RS-232 (5 V)

# OPTICAL SPECIFICATION

Fan angles <sup>(3)</sup>	Degrees	5°, 10°, 20°, 30°, 45°, 60°, 75°, 90° (homogeneous lines) 3°, 5°, 10°, 15°, 20°, 30°, 90° (Gaussian line profile)
Line straightness (4)	% (of line length)	< 0.05 %
Line uniformity (5)	% (typical)	< 25 %
Dot		Point elliptical
DOE		Multi line, crosses, grids, etc.
Focus range	mm	100 mm up to 10,000 mm (or fixed focus available)

#### KEYNOTES

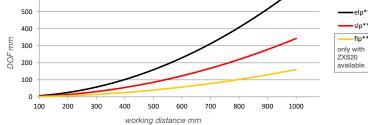
(1) Boresight error	Also known as pitch and skew.
<sup>(2)</sup> Line orientation	Also known as line tilt (roll) with reference to the indentation in the clamping area
<sup>(3)</sup> Line length / fan angle	at > 13.5 % I <sub>max</sub>
<sup>(4)</sup> Line straightness	Deviation from best fit line over the middle 80% of the line, for homogeneous lines
<sup>(5)</sup> Line uniformity	Maximum relative optical power variation over the middle 80% of the line, for homogeneous lines and fixed focus



#### LINE WIDTH VS. WORKING DISTANCE\* 300 µm (FWHM) 250 200 150 vidth 100 50 Line 0 100 200 300 400 500 600 700 800 900 1000

working distance mm

#### **DOF VS. WORKING DISTANCE\***



Calculation factor for line width Calculation factor for depth of focus Wavelength flp\*\* slp\*\* elp\*\* flp\*\* slp\*\* elp\*\* Blue 405 nm 0.66 0.62 0.82 0.75 0.70 1.02 Blue 450 nm 1.03 0.67 1.83 1.49 0.74 4.29 520 nm 0.97 0.78 1.20 0.99 0.80 2.61 Green 1.28 0.70 0.95 Red 640 nm 1.05 1.00 1.04 Red 660 nm 1.00 1.00 1.00 1.00 1.00 1.00 830 nm IR 2.11 2.20 1.42 1.30 1.71 1.03

Optical configurations for several line settings are available.

- flp\*\* = fine line Powell; thin lines for all working distances with smaller depth of focus (recommended for fan angles between

5° - 60° at working distances < 500 mm and for fan angle of 90° at working distances > 500 mm). Only available with ZXS20.

This optical configuration cannot supply the maximum output mentioned on page 2. Only approx. 75% can be achieved. - slp\*\* = standard line Powell; standard setup with medium line thickness and depth of focus.

- elp\*\* = extended line Powell; lines with advanced depth of focus and thicker lines. Recommended for fan angles > 75° at working distances < 500 mm. The graphs above show the values for line width and depth of focus of a 660 nm laser. To get the values for a different wavelength the factor from the table above has to be multiplied by the values from the graphs.

Example: 660 nm laser focused at 1 m working distance: line width approx. 200 µm (@ slp\*\* optic); Depth of focus approx. 350 mm (values from the graphs)

Calculated: 450 nm laser focused at 1 m working distance: line width approx. 200 µm x 0.67 = 134 µm; Depth of focus approx. 350 mm x 0.74 = 259 mm

\* Values in the graphs for homogenous line profiles.

\*\* Fan angle: 5° - 90°

#### SOFTWARE

GUI Serial communication I2C, RS-232 (5 V)

# ANALOG MODULATION

Features (e. g.):

Maximum bandwidth	< 10 Hz		
Linearity	< 5 % (from 10 % to 100 % of laser power)		
Active range	0 - 2 VDC		
Impedance	100 k $\Omega$ to internal VCC (3.3 V)		
Operation range	0 - 30 VDC		

# **DIGITAL MODULATION** Maximum fue automatic

Maximum frequency	up to 150 KHz		
Rise time (Mod High ➡ 90%)	< 160 ns		
Fall time (Mod Low ⇒ 10%)	<100 ns		
Signaling levels	VIL_max < +0.9 V VIH_min > +2.2 V		
Operation range	0 - 30 VDC		

#### **ENVIRONMENTAL CONDITIONS**

Operating temperature	°C / °F	
Storage temperature	°C / °F	
Humidity	%	
Dissipated heat	W	
Shock and vibration		

-10 °C to +50 °C / 14 °F to +122 °F

- Status query

- Intensity control

-

-

Output power control

System configuration Digital Modulation

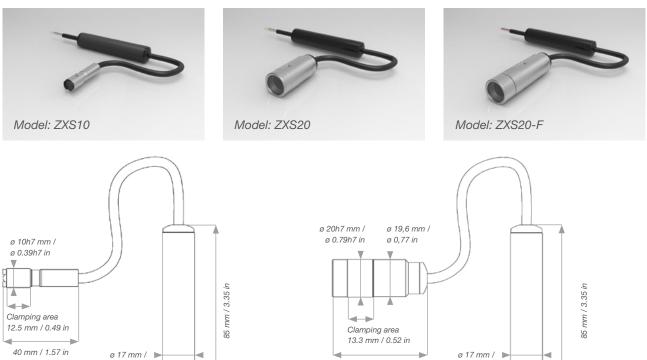
Weighted end of life indication

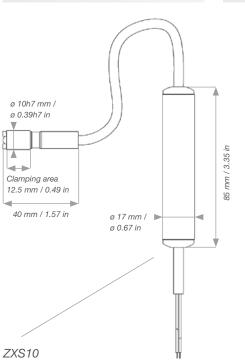
-40 °C to +85 °C / -40 °F to +185 °F	
< 90 %, non-condensing	
Max. 4 W	
According to IEC EN 61373:2011, cat. 2	

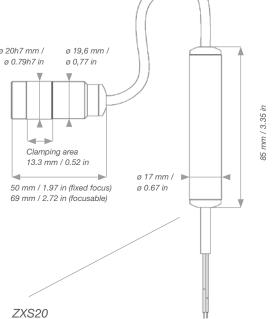


#### MECHANICAL SPECIFICATIONS - DEPENDING ON LASER HEAD VERSION

/eight ead: lectronics:	g / lbs g / lbs	 ZXS10 8 g / 0.02 lbs 40 g / 0.09 lbs	ZXS20 110 g / 0.24 lbs 40 g / 0.09 lbs	ZXS20-F 155 g / 0.34 lbs 40 g / 0.09 lbs
ength	mm / inch	please see technical draw	wing below	
Diameter head ø	mm / inch	 please see technical drav	wing below	
ength of cable between optics and electronics	mm / inch	100 mm / 3.53 in (others	on request)	
ength of connection cable	mm / inch	2,000 mm / 78.74 in (othe	ers on request)	
/laterial		Stainless steel (laser head	d) / aluminum (housing of	f electronics)
Protection class		IP 50 (IP 67 optional)	IP 67	IP 67







## 6-LEAD CABLE

X 1.1 brown	405 nm - 520 nm: 9 - 30 VDC, 15 VA	635 nm - 830 nm: 5 - 30 VDC, 15 VA
X 1.2 orange	Digital modulation TTL	
X 1.3 black	GND	
X 1.4 yellow	Analog modulation (0-2 VDC)	
X 1.5 green	Fail out (open-drain)	
X 1.6 red	Shielding	
Coding scheme shows de	ault configuration at delivery, individual se	up possible.

CE-Conformity according to the directives 2014/30/EU, 2011/65/EU and 2006/25/EU. Subject to technical change. Version: June 2018